



IEEE EDS Kansai Chapter

IMFEDK Best Paper Award (Oral Presentation)

R11 “Characterization of resistive switching phenomena in thermal silicon oxide RRAM devices by means of small-signal measurements”

Piotr Wiśniewski
(Warsaw University of Technology)



IEEE EDS Kansai Chapter

IMFEDK Student Paper Award (Poster Presentation)

P04 “The Origin of Diamond/ Al_2O_3 Interface
Defects Analysis”

Masaki Matsumoto
(Kindai University)



IEEE EDS Kansai Chapter

**IMFEDK Student Paper Award
(Poster Presentation)**

P18 “Low-temperature fabrication process of In₂O₃ thin-film transistors using aqueous precursor solution and excimer light”

Takeaki Komai
(Osaka Institute of Technology)

Congratulations !